

Q5
a) density of states $D(E) = \frac{\text{no. of states b/w } E \text{ \& } E + \Delta E}{V \times \Delta E}$

Now, we know each point in 3D k -space plot, represents an allowed energy / quantum state corresponding to various integral values of n_x and n_y . Positive & negative values of k_x , k_y and k_z have same energy.

Now for the derivation
let the distance b/w any two quantum states in the k_x direction is

$$k_{x+1} - k_x = (n_x + 1) \frac{\pi}{a} - n_x \left(\frac{\pi}{a} \right) = \pi/a$$

Similarly,

$$k_{y+1} - k_y = (n_y + 1) \pi/a - n_y (\pi/a) = \pi/a$$

$$k_{z+1} - k_z = (n_z + 1) (\pi/a) - n_z (\pi/a) = \pi/a$$

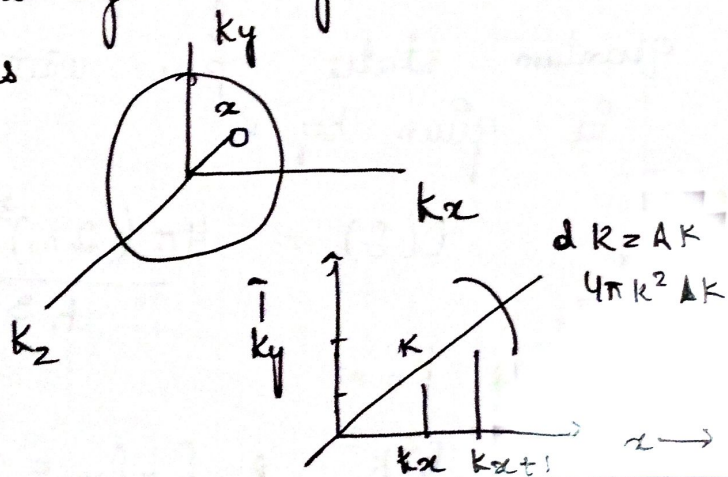
So, volume of single quantum state V_k is

$$V_k = \left(\pi/a \right)^3$$

A volume in k space is given by $4\pi k^2 dk$.

So, density of quantum states
 $D(k) dk$ in k space is

$$D(k) dk = 2 \times \frac{1}{8} \left(\frac{4\pi k^2 dk}{(\pi/a)^3} \right)$$



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∴ factors 2 takes into 2 spin states allowed for each quantum states factor 1/2 takes into account that only the values of k_x and k_y and k_z are considered.

$$\therefore D(k) dk = \frac{\pi k^2 dk}{(\pi/a)^3} \dots$$

for free electron, $E = \frac{\hbar^2 k^2}{2m} \Rightarrow k = \frac{\sqrt{2mE}}{\hbar}$

$$\frac{dk}{dE} = \frac{\sqrt{2m}}{\hbar} \times \frac{1}{2} E^{-1/2}$$

$$\Rightarrow dk = \frac{1}{\hbar} \sqrt{\frac{m}{2E}} dE$$

Now,

$$D(E) dE = \frac{a^3}{\pi^2} \left(\frac{2mE}{\hbar^2} \right) \frac{1}{\hbar} \sqrt{\frac{m}{2E}} dE$$

$$\Rightarrow D(E) dE = \frac{4\pi a^3}{\hbar^3} (2m)^{3/2} \sqrt{E} dE$$

$E \rightarrow$ total no. of quantum states.
Quantum states per unit volume per unit energy is given by,

$$D(E) = \frac{4\pi (2m)^{3/2}}{\hbar^3} \cdot \sqrt{E}$$

Now, we know.

$$E - E_c = \frac{\hbar^2 k^2}{2m^*} \quad \& \quad E - E_v = -\frac{\hbar^2 k^2}{2m^*}$$

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So,

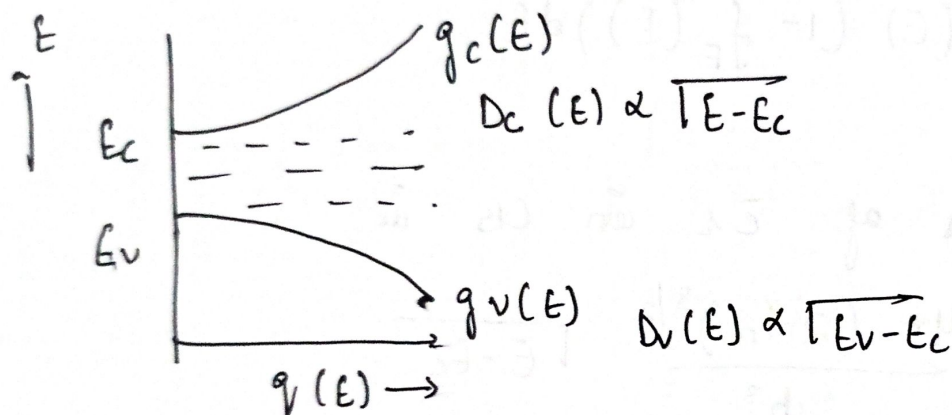
$$D_c(E) = \frac{4\pi (2m_n^*)^{3/2}}{h^3} \sqrt{E - E_c} \quad ; \quad E > E_c$$

Similarly,

$$D_v(E) = \frac{4\pi (2m_p^*)^{3/2}}{h^3} \sqrt{E_v - E} \quad ; \quad E < E_v$$

in the forbidden band energy levels are not allowed so,

$$D(E) = 0 \quad ; \quad E_v < E < E_c$$



if $m_n^* = m_p^*$
then $D_c(E)$ and $D_v(E)$
are symmetrical.

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⑤ Total \bar{e} conc. per unit volume

$$n(E) = \int_{E_c}^{\infty} D_c(E) \cdot f_F(E) dE = \int_{E_c}^{\infty} D_c(E) \cdot f_F(E) dE$$

Similarly, the total hole concentration per unit volume, $P(E)$ in VB is

$$P(E) = \int_{-\infty}^{E_v} D_v(E) (1 - f_F(E)) dE$$

bottom of VB

$$= \int_{-\infty}^{E_v} D_v(E) (1 - f_F(E)) dE$$

Density of states of \bar{e} s in CB is

$$D_c(E) = \frac{4\pi (2m_n^*)^{3/2}}{h^3} \sqrt{E - E_c}$$

So,

$$n(E) = \int_{E_c}^{\infty} \frac{4\pi (2m_n^*)^{3/2}}{h^3} \sqrt{E - E_c} \cdot \frac{1}{1 + e^{(E - E_F)/k_B T}} dE$$

So,

[$\therefore E - E_F \gg k_B T$]

$$n(E) = \int_{E_c}^{\infty} \frac{4\pi (2m_n^*)^{3/2}}{h^3} \sqrt{E - E_c} \cdot e^{-\frac{(E - E_F)}{k_B T}} d(E - E_c)$$

Let $U = \frac{E - E_c}{k_B T}$

$$n(E) = 4\pi \left(\frac{2m_n^* k_B T}{h^3} \right)^{3/2} \cdot e^{-\frac{(E_c - E_F)}{k_B T}} \int_0^{\infty} \sqrt{U} e^{-U} dU$$

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The integral is the gamma function with a value of $\Gamma(\pi/2)$

So, $n \approx n(E) = 2 \left(\frac{2\pi m_n^* k_B T}{h^2} \right)^{3/2} e^{-\frac{(E_c - E_F)}{k_B T}}$

Similarly, we can find

holes concentration $p = 2 \left(\frac{2\pi m_p^* k_B T}{h^2} \right)^{3/2} e^{-\frac{(E_F - E_v)}{k_B T}}$

Since n and holes conc. are equal in intrinsic semiconductor i.e. $n = p$

$$\Rightarrow 2 \left(\frac{2\pi m_n^* k_B T}{h^2} \right)^{3/2} \cdot e^{-\frac{(E_c - E_F)}{k_B T}} = 2 \left(\frac{2\pi m_p^* k_B T}{h^2} \right)^{3/2} \cdot e^{-\frac{(E_F - E_v)}{k_B T}}$$

$$\Rightarrow e^{-\frac{(E_c - E_F) + (E_F - E_v)}{k_B T}} = \left(\frac{m_p^*}{m_n^*} \right)^{3/2}$$

$$\Rightarrow -\frac{(E_c - E_F) + (E_F - E_v)}{k_B T} = \frac{3}{2} \ln \left(\frac{m_p^*}{m_n^*} \right)$$

$$2 E_F - (E_c + E_v) = \frac{3}{2} k_B T \ln \left(\frac{m_p^*}{m_n^*} \right)$$

$$E_F = \frac{(E_c + E_v)}{2} + \frac{3}{4} k_B T \ln \left(\frac{m_p^*}{m_n^*} \right)$$

if $m_p^* = m_n^*$ then Fermi level is exactly in center of bandgap (E_g)

$m_p^* > m_n^*$, Fermi level is slightly above centre of g .

$m_p^* < m_n^*$ it is slightly below centre of equation